

SANYO Semiconductors DATA SHEET



N-Channel Silicon MOSFET MCH6652 — General-Purpose Switching Device **Applications**

Features

• 4V drive.

Composite type with 2 MOSFETs contained in a single package, facilitating high-density mounting.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		30	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	ID		300	mA
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	1.2	А
Allowable Power Dissipation	PD	When mounted on ceramic substrate (900mm ² ×0.8mm) 1unit	0.6	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0V	30			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =30V, V _{GS} =0V			1	μΑ
Gate-to-Source Leakage Current	IGSS	VGS=±16V, VDS=0V			±10	μΑ
Cutoff Voltage	VGS(off)	V _{DS} =10V, I _D =100μA	1.2		2.6	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =150mA	170	290		mS
Static Drain-to-Source On-State Resistance	RDS(on)1	ID=150mA, VGS=10V		660	900	mΩ
	R _{DS} (on)2	ID=80mA, VGS=4V		1.5	2.2	Ω
Input Capacitance	Ciss	V _{DS} =10V, f=1MHz		22		pF
Output Capacitance	Coss	VDS=10V, f=1MHz		7.5		pF
Reverse Transfer Capacitance	Crss	V _{DS} =10V, f=1MHz		3.6		pF

Marking : XD

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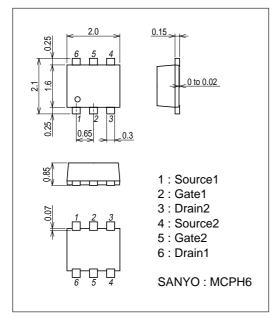
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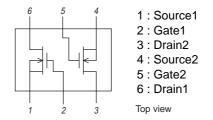
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Turn-ON Delay Time	t _d (on)	See specified Test Circuit.		14		ns
Rise Time	tr	See specified Test Circuit.		17.5		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		65		ns
Fall Time	tf	See specified Test Circuit.		41		ns
Total Gate Charge	Qg	V _{DS} =10V, V _{GS} =10V, I _D =300mA		1.68		nC
Gate-to-Source Charge	Qgs	V _{DS} =10V, V _{GS} =10V, I _D =300mA		0.54		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =10V, V _{GS} =10V, I _D =300mA		0.12		nC
Diode Forward Voltage	V _{SD}	I _S =300mA, V _{GS} =0V		0.86	1.2	V

Package Dimensions

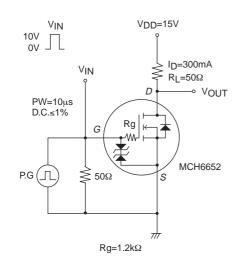
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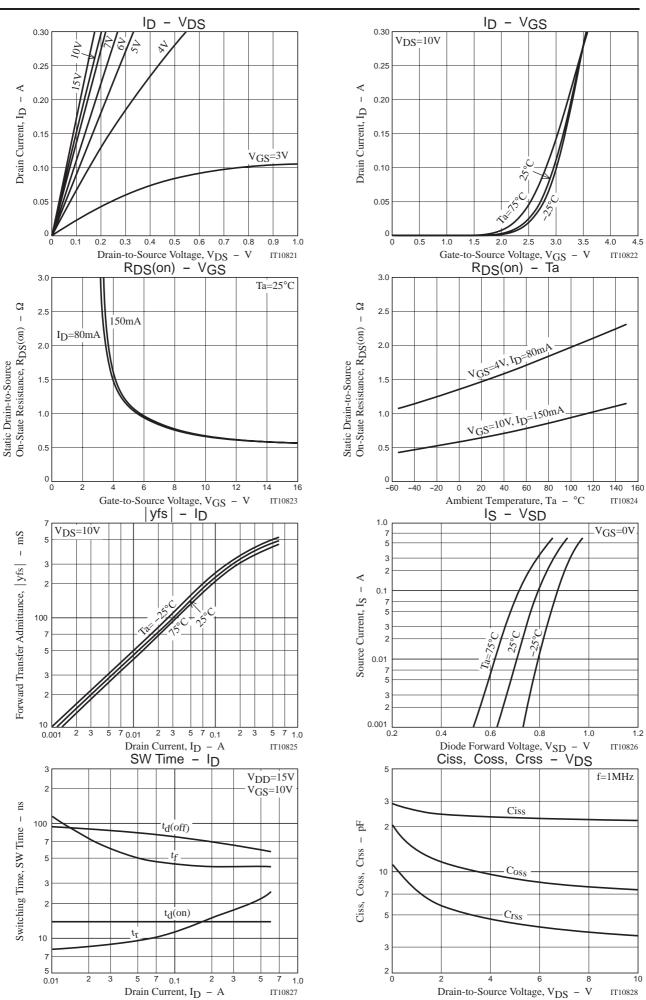


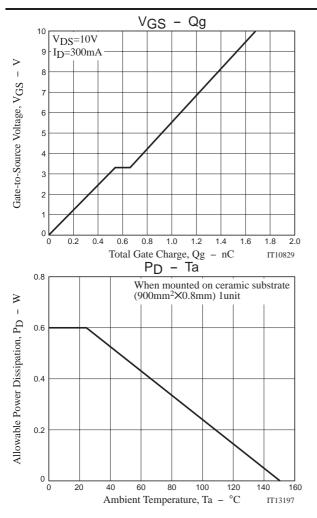
Electrical Connection

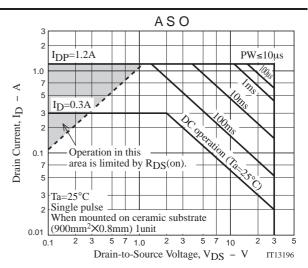


Switching Time Test Circuit









Note on usage : Since the MCH6652 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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